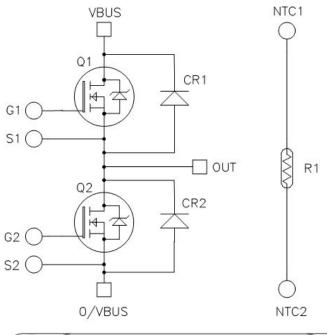
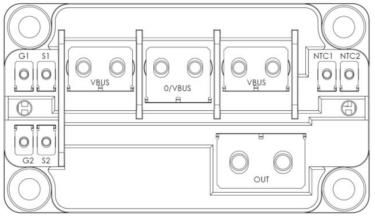


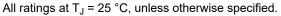
Very Low Stray Inductance Phase Leg SiC MOSFET Power Module

Product Overview

The MSCSM170AM029CT6LIAG device is a very low stray inductance phase leg 1700 V, 676 A silicon Carbide (SiC) MOSFET power module.







Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM170AM029CT6LIAG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF
- Very low stray inductance
- Internal thermistor for temperature monitoring
- M4 and M5 power connectors
- M2.5 signal connectors
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM170AM029CT6LIAG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Low profile
- RoHS Compliant

Application

The following are the applications of MSCSM170AM029CT6LIAG device:

- · Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM170AM029CT6LIAG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM170AM029CT6LIAG device.

Symbol Parameter **Maximum Ratings** Unit V_{DSS} Drain-source voltage 1700 V Continuous drain current T_C = 25 °C 676 А I_D T_C = 80 °C 538 I_{DM} Pulsed drain current 1350 -10/23 V V_{GS} Gate-source voltage R_{DS(on)} Drain-source ON resistance 3.75 mΩ T_C = 25 °C 3000 W Power dissipation P_D

Table 1-1. Absolute Maximum Ratings

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM170AM029CT6LIAG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0 V; V _{DS} = 1700 V	V	_	120	1200	μA
R _{DS(on)}	Drain-Source on	V _{GS} = 20 V	T _J = 25 °C	_	2.9	3.75	mΩ
	resistance	I _D = 360 A	T _J = 175 °C	_	5.1	_	
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}; I_D = 30 \text{ mA}$		1.8	3.3		V
I _{GSS}	Gate–Source leakage current	V _{GS} = 20 V; V _{DS} = 0 V		_	_	1200	nA

Table 1-2. Electrical Characteristics

Electrical Specifications

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM170AM029CT6LIAG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
C _{iss}	Input capacitance	V _{GS} = 0 V		-	39.6	—	nF
C _{oss}	Output capacitance	V _{DS} = 1000 V		—	1.8	—	
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	0.12		
Qg	Total gate charge	V_{GS} = -5 V/20 V		-	2136	—	nC
Q _{gs}	Gate-source charge	V _{Bus} = 850 V		_	588	_	
Q _{gd}	Gate-drain charge	I _D = 360 A		_	324	—	
T _{d(on)}	Turn-on delay time	T _J = 150 °C		_	74	_	ns
Tr	Rise time	V _{GS} = -5 V/20 V		_	63	—	
T _{d(off)}	Turn-off delay time	V _{Bus} = 900 V		_	163	_	
T _f	Fall time	I _D = 600 A R _G = 0.5 Ω			48	_	
Eon	Turn-on energy	V _{GS} = -5 V/20 V	T _J = 150 °C	_	24.2	_	mJ
E _{off}	Turn-off energy	V _{Bus} = 900 V I _D = 600 A R _G = 0.5 Ω	T _J = 150 °C	_	12.6	_	
R _{Gint}	Internal gate resistance	9		_	0.79	_	Ω
R _{thJC}	Junction-to-case therm	al resistance		—	_	0.05	°C/W

Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM170AM029CT6LIAG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
V_{SD}	Diode forward voltage	V _{GS} = 0 V; I _{SD} = 360 A	—	3.7	_	V
		V_{GS} = -5 V; I _{SD} = 360 A		3.9		-
t _{rr}	Reverse recovery time	I_{SD} = 360 A; V_{GS} = -5 V	—	27	_	ns
Q _{rr}	Reverse recovery charge	V _R = 900 V; di _F /dt = 1200 A/µs	—	7.8	—	μC
Irr	Reverse recovery current		_	552		A

1.2 SiC Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics of the MSCSM170AM029CT6LIAG device.

Table 1-5. S	SiC Diode Ratings	and Characteristics	(Per SiC Diode)
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Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Peak repetitive reverse vol	tage		—	—	1700	V
I _{RRM}	Reverse leakage current	V _R = 1700 V	T _J = 25 °C	_	300	1200	μA
			T _J = 175 °C		1500	—	
I _F	DC forward current	<u> </u>	T _C = 125 °C	_	300	—	A
V _F	Diode forward voltage	I _F = 300 A	T _J = 25 °C		1.5	1.8	V
			T _J = 175 °C	_	2	—	
Q _C	Total capacitive charge	V _R = 900 V		_	2460	_	nC
С	Total capacitance	f = 1 MHz, V _R = 6	000 V	_	1800	—	pF
		f = 1 MHz, V _R = 9	900 V	_	1500	_	
R _{thJC}	Junction-to-case thermal re	esistance		_	-	0.062	°C/W

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM170AM029CT6LIAG device.

Table 1-6. Thermal and Package Characteristics

Symbol	Characteristic			Min	Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to ca	se t = 1 min, 5	60 Hz/60 Hz	4000	—	V
TJ	Operating junction temperature range			-40	175	°C
T _{JOP}	Recommended junction temperature und	er switching c	onditions	-40	T _{Jmax} –25	
T _{STG}	Storage case temperature			-40	125	
T _C	Operating case temperature			-40	125	
Torque	Mounting torque	For	M2.5	0.4	0.6	N.m
		terminals	M4	2	3	
			M5	2	3.5	
		To heatsink	M6	3	5	
L _{DC}	Module stray inductance between V_{Bus} as	nd 0/V _{Bus}			3	nH
Wt	Package weight				320	g

Electrical Specifications

The following table lists the temperature sensor NTC of the MSCSM170AM029CT6LIAG device.

Table 1-7. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25 °C	—	—	50	—	kΩ
$\Delta R_{25}/R_{25}$	—	—	_	5		%
B _{25/85}	T ₂₅ = 298.15 K	—		3952		К
ΔΒ/Β	—	T _C = 100 °C		4		%

 $R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$ T: Thermistor temperature R_T: Thermistor value at T

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.4 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM170AM029CT6LIAG device.

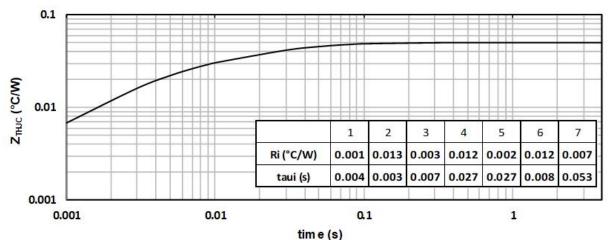
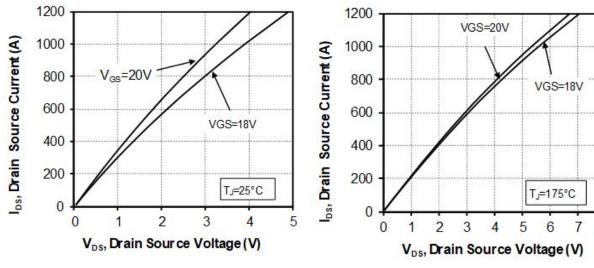
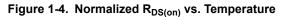


Figure 1-1. Maximum Thermal Impedance

Electrical Specifications

8





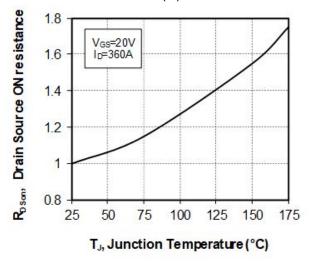


Figure 1-5. Transfer Characteristics

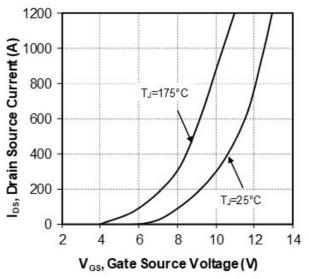


Figure 1-3. Output Characteristics, T_J = 175 °C

Electrical Specifications

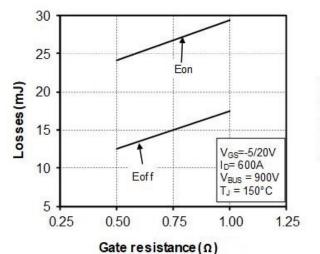
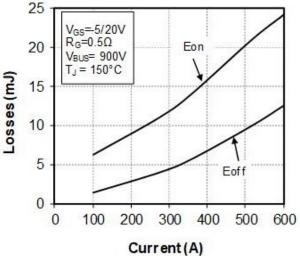
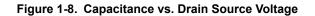


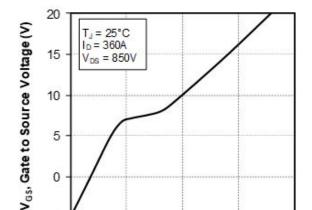


Figure 1-7. Switching Energy vs. Current





100000

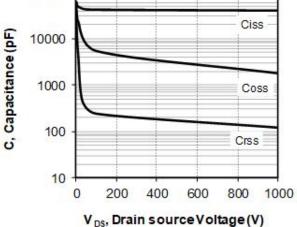


1200

Gate Charge (nC)

600

Figure 1-9. Gate Charge vs. Gate Source Voltage



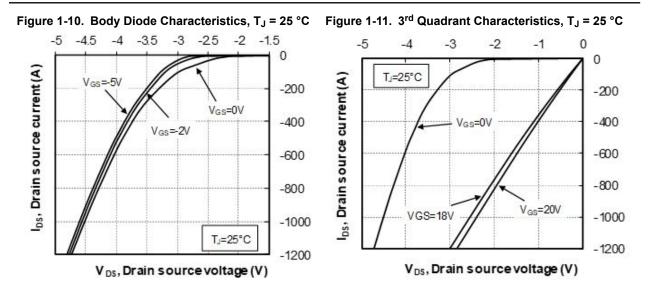
-5

0

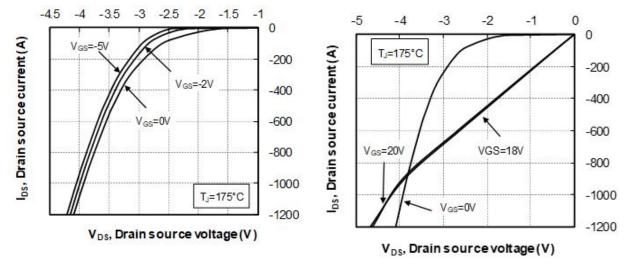
1800

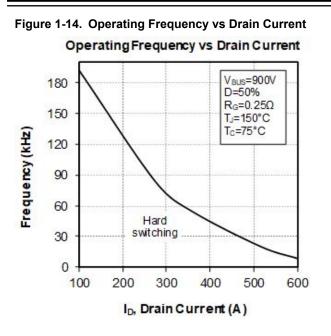
2400

Electrical Specifications









1.5 Typical SiC Diode Performance Curves

This section shows the typical SiC diode performance curves of the MSCSM170AM029CT6LIAG device.

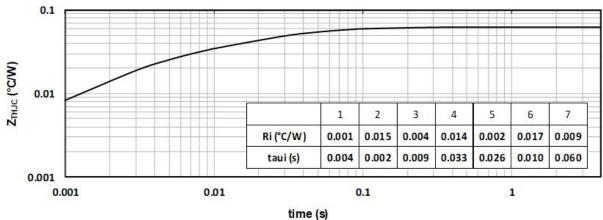
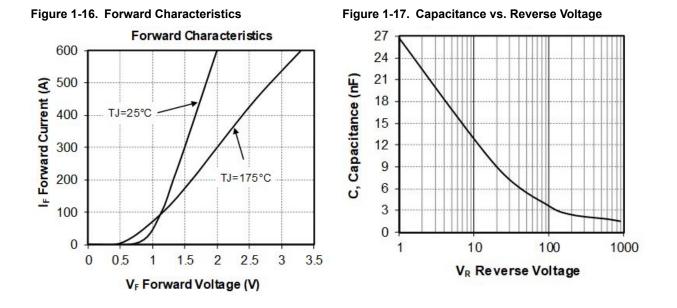


Figure 1-15. Maximum Thermal Impedance

Electrical Specifications



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Package Specifications

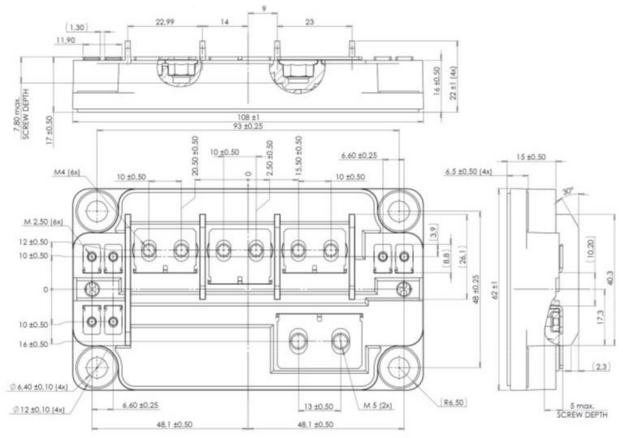
2. Package Specifications

The following section shows the package specification of the MSCSM170AM029CT6LIAG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM170AM029CT6LIAG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See AN1911—Mounting Instructions for SP6 Low Inductance Power Module for more information.

Revision History

3. Revision History

Revision	Date	Description
A	04/2021	This is the first publication of this document.

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